



DP350T05

PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (DN350T05)
- Ideal for Medium Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 2, 3 and 4)
- Qualified to AEC-Q101 Standards for High Reliability

B TOP VIEW E B TOP VIEW E C C

SOT-23							
Dim	Min	Max					
Α	0.37	0.51					
В	1.20	1.40					
C	2.30	2.50					
D	0.89	1.03					
E	0.45	0.60					
G	1.78	2.05					
Н	2.80	3.00					
7	0.013	0.10					
K	0.903	1.10					
L	0.45	0.61					
M	0.085	0.180					
α	0°	8°					
All Dimensions in mm							

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: K3U See Page 2
- Ordering & Date Code Information: See Page 2
- Weight: 0.008 grams (approximate)

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	DP350T05	Unit	
Collector-Base Voltage	V _{CBO}	-350	V	
Collector-Emitter Voltage	V _{CEO}	-350	V	
Emitter-Base Voltage	V _{EBO}	-5.0	V	
Continuous Collector Current (Note 1)	I _C	-500	mA	
Power Dissipation (Note 1)	P _D	300	mW	
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	417	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead. Halogen and Antimony Free.
- 3. Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product is manufactured with Green Molding Compound and does not contain Halogens or Sb₂O₃ Fire Retardants.

DS30624 Rev. 7 - 2 1 of 4 DP350T05
© Diodes Incorporated



Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-350	_	V	$I_C = -100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-350	_	V	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	-50	nA	V _{CB} = -200V, I _E = 0
Collector Cutoff Current	I _{EBO}	_	-50	nA	$V_{CE} = -3.0V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)					
		20	_		$I_C = -1.0 \text{mA}, V_{CE} = -10 \text{V}$
		30	_		$I_C = -10 \text{mA}, V_{CE} = -10 \text{V}$
DC Current Gain	h _{FE}	30	200	_	$I_C = -30 \text{mA}, V_{CE} = -10 \text{V}$
		20	200		$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
		15	_		$I_C = -100 \text{mA}, V_{CE} = -10 \text{V}$
			-0.30		$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$
Collector Emitter Seturation Voltage	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	_	-0.35	V	$I_C = -20 \text{mA}, I_B = -2.0 \text{mA}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.50	V	$I_C = -30 \text{mA}, I_B = -3.0 \text{mA}$
			-1.0		$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
			-0.75	V	$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-0.85		$I_C = -20 \text{mA}, I_B = -2.0 \text{mA}$
-	(- /	_	-0.90		$I_C = -30 \text{mA}, I_B = -3.0 \text{mA}$
Base-Emitter On Voltage	V _{BE(ON)}		-2.0	V	I _C = -100mA, V _{CE} = -10V
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}		7.0	pF	$V_{CB} = -20V$, $f = 1.0MHz$, $I_E = 0$
Transition Frequency	f⊤	50	_	MHz	$V_{CE} = -10V, I_{C} = -20mA$

Notes: 5. Short duration pulse test used to minimize self-heating effect.

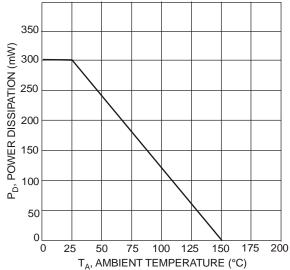


Fig. 1, Max Power Dissipation vs. Ambient Temperature

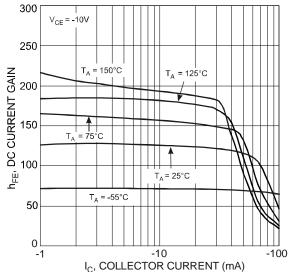
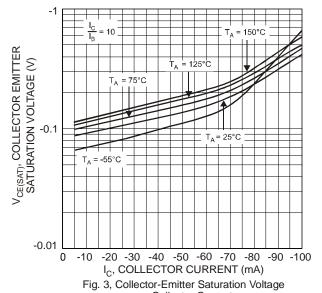
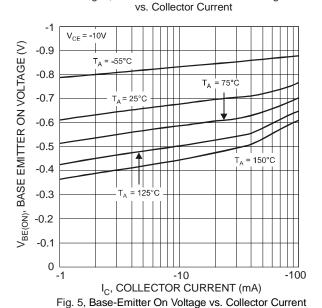


Fig. 2, DC Current Gain vs. Collector Current







-1

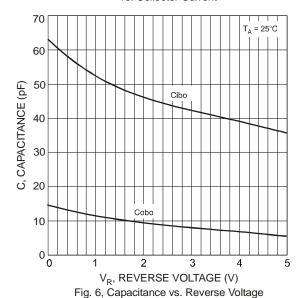
T_A = 25°C

T_A = 75°C

T_A = 125°C

T_A = 150°C

Fig. 4, Base Emitter Saturation Voltage vs. Collector Current

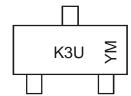


Ordering Information (Note 6)

Device	Packaging	Shipping		
DP350T05-7	SOT-23	3000/Tape & Reel		

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K3U = Product Type Marking Code YM = Date Code Marking Y = Year ex: S = 2005 M = Month ex: 9 = September

Date Code Key

Year	2005		2006	2007		2008	2009)	2010	2011		2012
Code	S		Т	U		V	W		Χ	Υ		Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

DS30624 Rev. 7 - 2 4 of 4 DP350T05
© Diodes Incorporated

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))